

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	V _{DSS}	-30	V
Gate-Source Voltage	V _{GSS}	±12	V
Drain Current (Note 5)	I _D	T _A = +25°C	A
		T _A = +70°C	
Drain Current (Note 5)	I _{DM}	-9	A
Body-Diode Continuous Current (Note 5)	I _S	-2.0	A

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	P _D	1.4	W
Thermal Resistance, Junction to Ambient @T _A = 25°C (Note 5)	R _{θJA}	90	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Notes: 5. Device mounted on FR-4 PCB. t ≤ 5 sec.

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)						
Drain-Source Breakdown Voltage	BV _{DSS}	-30	—	—	V	V _{GS} = 0V, I _D = -250μA
Zero Gate Voltage Drain Current	I _{DSS}	—	—	-1	μA	V _{DS} = -30V, V _{GS} = 0V
Gate-Body Leakage	I _{GSS}	—	—	±100	nA	V _{GS} = ±12V, V _{DS} = 0V
ON CHARACTERISTICS (Note 6)						
Gate Threshold Voltage	V _{GS(th)}	-0.6	—	-1.4	V	V _{DS} = V _{GS} , I _D = -250μA
Static Drain-Source On-Resistance	R _{DS(ON)}	—	—	120 240	mΩ	V _{GS} = -4.5V, I _D = -2.8A V _{GS} = -2.5V, I _D = -1.8A
Forward Transconductance	g _{fs}	—	5	—	S	V _{DS} = -5V, I _D = -2.8A
Source-Drain Diode Forward Voltage	V _{SD}	—	—	-1.1	V	V _{GS} = 0V, I _S = -2.0A
DYNAMIC CHARACTERISTICS (Note 7)						
Input Capacitance	C _{iss}	—	285	—	pF	V _{DS} = -15V, V _{GS} = 0V f = 1.0MHz
Output Capacitance	C _{oss}	—	56	—	pF	
Reverse Transfer Capacitance	C _{rss}	—	40	—	pF	
Gate Resistance	R _G	—	13	—	Ω	V _{DS} = 0V, V _{GS} = 0V f = 1.0MHz
SWITCHING CHARACTERISTICS (Note 7)						
Turn-On Delay Time	t _{d(on)}	—	5.6	—	ns	V _{DS} = -15V, V _{GS} = -4.5V, I _D = -1A, R _G = 6.0Ω
Rise Time	t _r	—	6.8	—		
Turn-Off Delay Time	t _{d(off)}	—	35.3	—		
Fall Time	t _f	—	19.2	—		
Total Gate Charge	Q _G	—	6.7 3.0	—	nC	V _{DS} = -15V, V _{GS} = -10V, I _D = -1.0A
Gate-Source Charge	Q _{GS}	—	0.8	—		V _{DS} = -15V, V _{GS} = -4.5V, I _D = -1.0A
Gate-Drain Charge	Q _{GD}	—	0.5	—		

Notes: 6. Short duration pulse test used to minimize self-heating effect.
7. Guaranteed by design. Not subject to production testing.

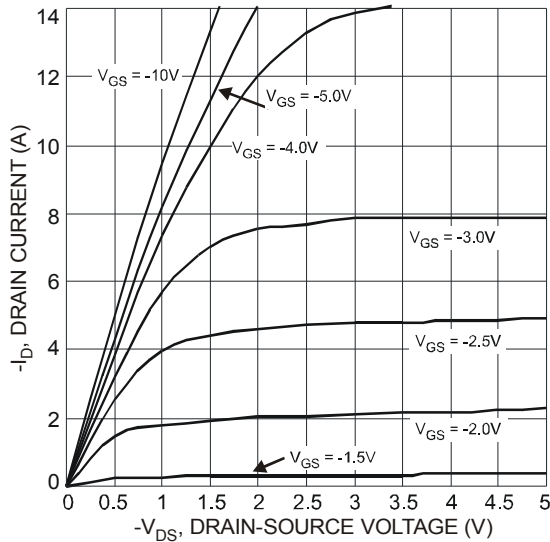


Fig. 1 Typical Output Characteristics

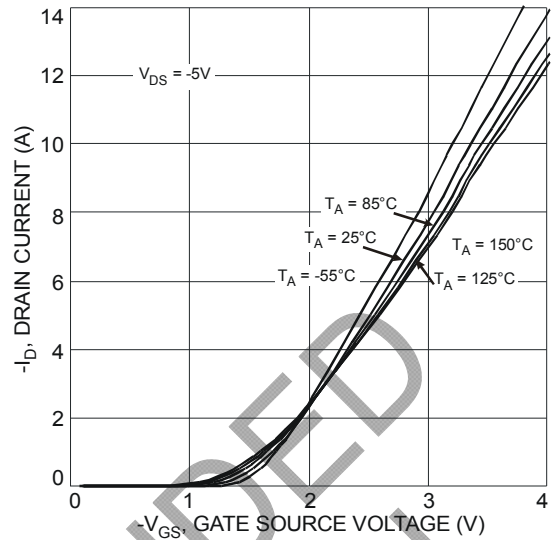


Fig. 2 Typical Transfer Characteristics

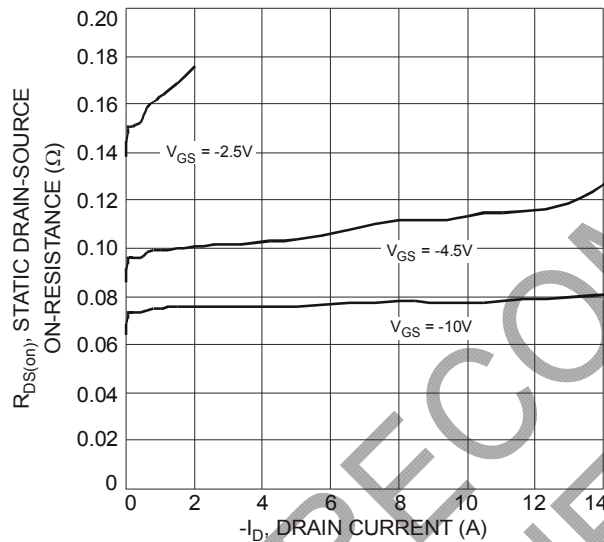


Fig. 3 On-Resistance vs. Drain Current and Gate Voltage

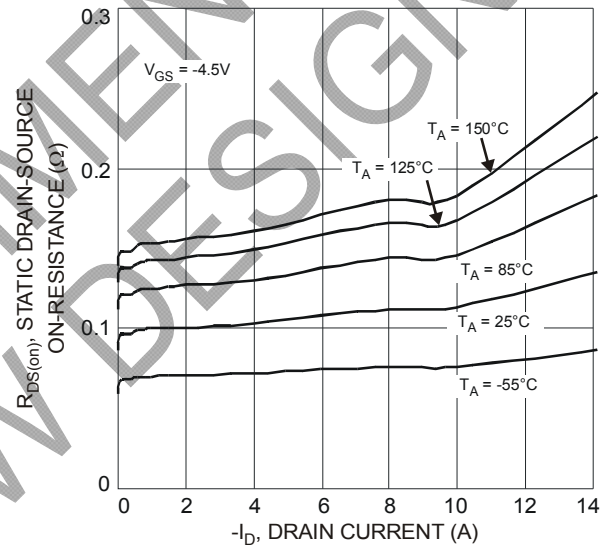


Fig. 4 On-Resistance vs. Drain Current and Temperature

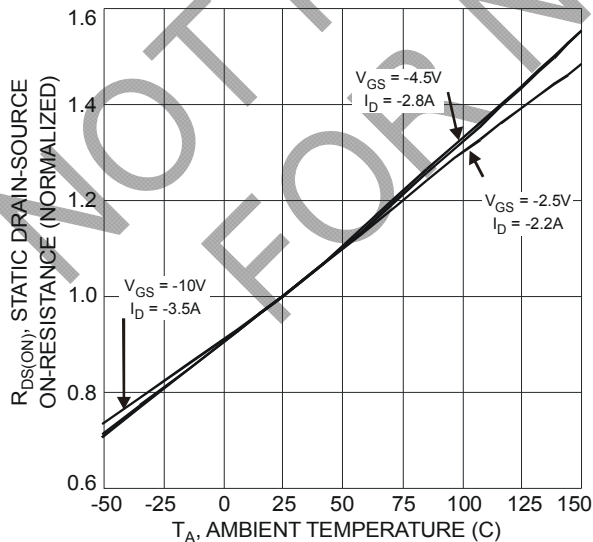


Fig. 5 Normalized Static Drain-Source On-Resistance vs. Ambient Temperature

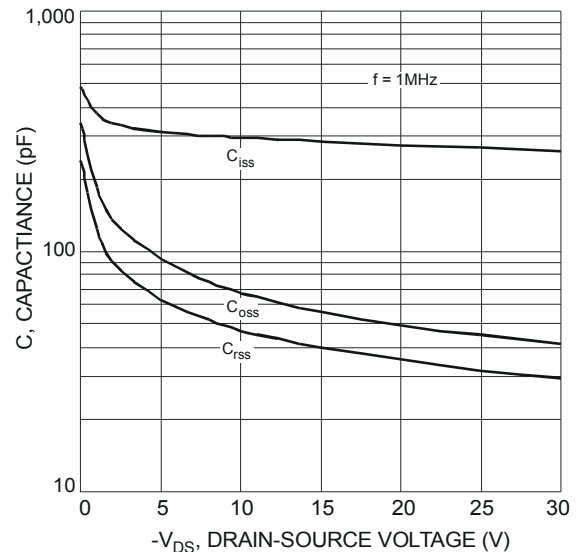


Fig. 6 Typical Capacitance

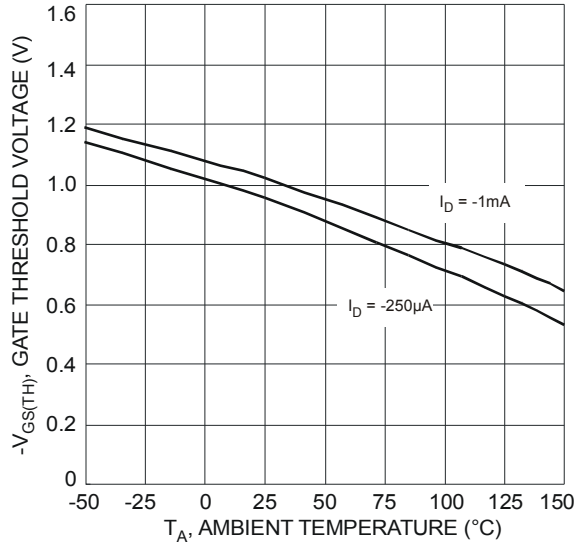


Fig. 7 Gate Threshold Voltage vs. Ambient Temperature

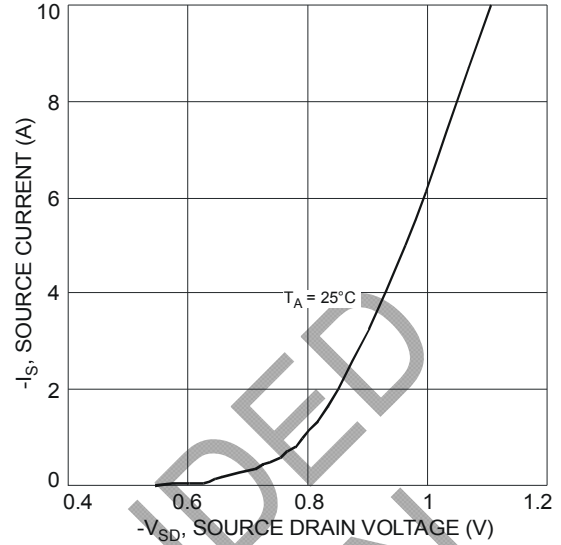
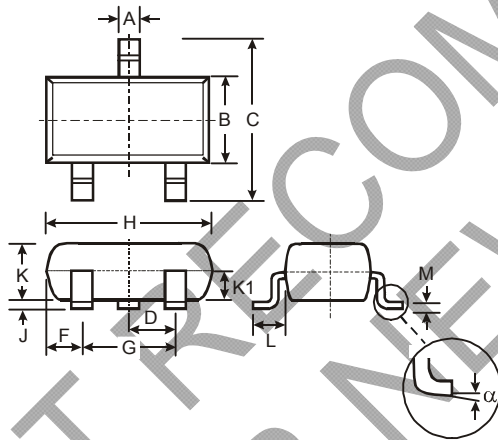


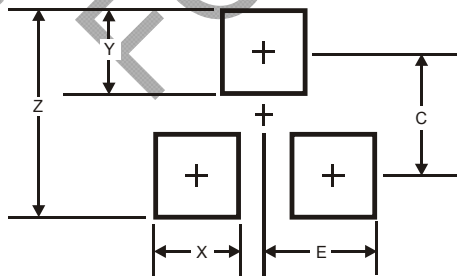
Fig. 8 Reverse Drain Current vs. Source-Drain Voltage

Package Outline Dimensions



SOT-23			
Dim	Min	Max	Typ
A	0.37	0.51	0.40
B	1.20	1.40	1.30
C	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
H	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.903	1.10	1.00
K1	-	-	0.400
L	0.45	0.61	0.55
M	0.085	0.18	0.11
α	0°	8°	-
All Dimensions in mm			

Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.9
X	0.8
Y	0.9
C	2.0
E	1.35

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